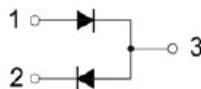
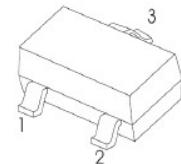


**SOT-23**



Marking: M5C

**SOT-23 Plastic-Encapsulate Switching Diode**

**特征 Features**

- 开关速度小于 4.0nS; Fast Switching Device (TRR <4.0 nS)
- 最大功率耗散 225mW; Power Dissipation of 225mW
- 高稳定性和可靠性。High Stability and High Reliability
- 反向漏电流小。Low reverse leakage

**机械数据 Mechanical Data**

- 封装: SOT-23 封装 SOT-23 Small Outline Plastic Package
- 环氧树脂 UL 易燃等级 Epoxy UL: 94V-0
- 安装位置: 任意 Mounting Position: Any

极限值和温度特性( $TA = 25^{\circ}\text{C}$  除非另有规定)

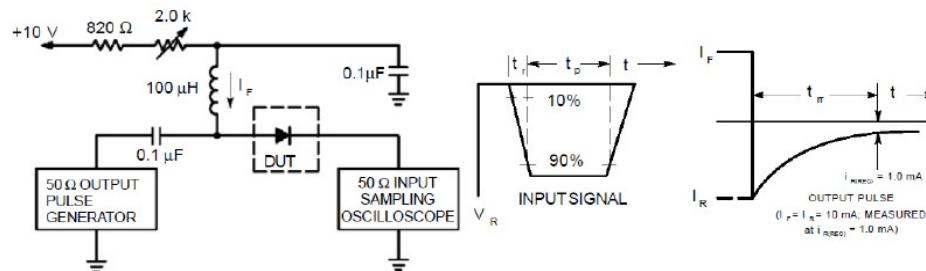
**Maximum Ratings & Thermal Characteristics** (Ratings at  $25^{\circ}\text{C}$  ambient temperature unless otherwise specified.)

参数 Parameters	符号 Symbol	数值 Value	单位 Unit
反向电压 Reverse Voltage	$V_R$	100	V
反向峰值电压 Peak Repetitive Reverse Voltage	$V_{RRM}$	100	V
功率消耗 Power Dissipation	$P_d$	225	mW
正向峰值浪涌电流 Peak Forward Surge Current	$I_{FPM}$	500	mA
工作结温 Operating junction temperature	$T_j$	150	$^{\circ}\text{C}$
存储温度 Storage temperature range	$T_s$	-55~+150	$^{\circ}\text{C}$
热阻抗 Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	417	$^{\circ}\text{C}/\text{W}$

Valid provided that electrodes are kept at ambient temperature.

**电特性 Electrical Characteristics** (Ratings at  $25^{\circ}\text{C}$  ambient temperature unless otherwise specified).

符号 Symbols	参数 Parameter	测试条件 Test Condition	界限 Limits		单位 Unit
			Min	Max	
$V(BR)$	反向电压 Reverse Voltage	$IR=100\mu\text{A}$	100		V
$I_R$	反向漏电流 Reverse Leakage Current	$VR=100\text{V}$	---	3.0	$\mu\text{A}$
		$VR=50\text{V}$	---	1	$\mu\text{A}$
$V_F$	正向电压 Forward Voltage	$IF=1\text{mA}$		0.72	
		$F=10\text{mA}$		0.82	
		$F=100\text{mA}$		1.10	V
$TRR$	反向恢复时间 Reverse Recovery Time	$IF= IR=10\text{mA}$	---	4	nS
		$VR=6\text{V}, RL=100\Omega$			
		$IRR=0.1 \times IR$			
$CT$	结电容 Capacitance	$VR=0\text{V}, f=1\text{MHZ}$	---	1.5	pF



Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 10mA.

2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 10mA.

3.  $t_p \gg t_r$

**Recovery Time Equivalent Test Circuit**

## Typical Characteristics

Fig.1 Typical Forward Characteristics

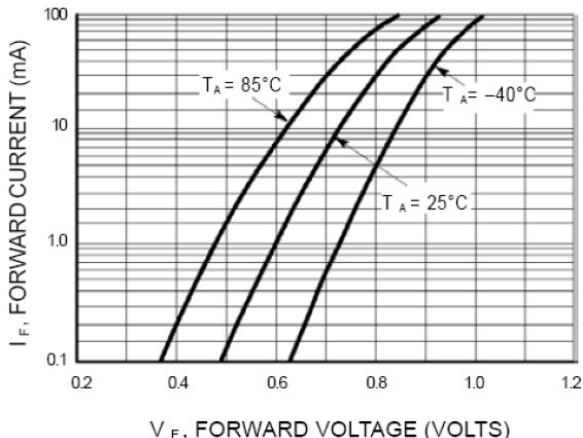


Fig.2 Typical Reverse Characteristics

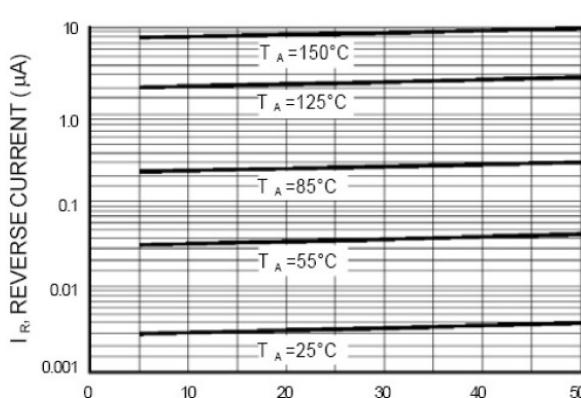
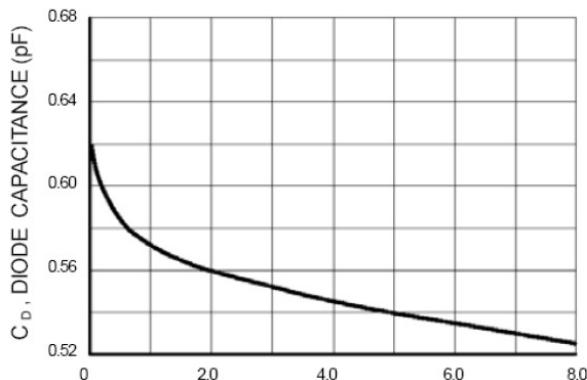
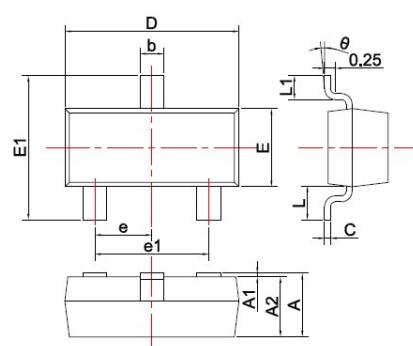


Fig.3 Typical Capacitance Characteristics



## SOT-23 PACKAGE OUTLINE

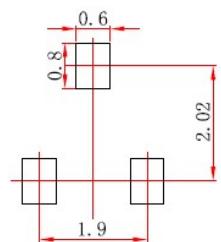
Plastic surface mounted package



SYMBOL	DIMENSIONS	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
$\theta$	0°	8°

Unit: mm

焊盘设计参考 Precautions: PCB Design(Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs)



Note:  
1. Controlling dimension: in millimeters.  
2. General tolerance:  $\pm 0.05$ mm.  
3. The pad layout is for reference purposes only.